

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **ESD Protected**
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**
- **PPAP Capable (Note 4)**

Mechanical Data

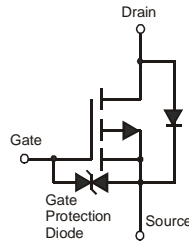
- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish - Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 **(e3)**
- Weight: 0.006 grams (Approximate)



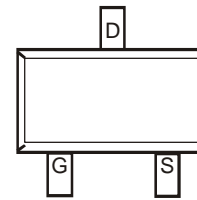
ESD PROTECTED



Top View



Equivalent Circuit



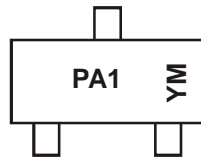
Top View

Ordering Information (Note 5)

| Part Number | Case | Packaging |
|---------------|--------|---------------------|
| DMG1013UWQ-7 | SOT323 | 3000 / Tape & Reel |
| DMG1013UWQ-13 | SOT323 | 10000 / Tape & Reel |

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html.
 5. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



PA1 = Product Type Marking Code
 YM = Date Code Marking
 Y = Year (ex: D = 2016)
 M = Month (ex: 9 = September)

Date Code Key

| Year | 2008 | ... | 2015 | 2016 | 2017 | 2018 | 2019 | 2020 | 2021 | 2022 | 2023 | 2024 |
|------|------|-----|------|------|------|------|------|------|------|------|------|------|
| Code | V | ... | C | D | E | F | G | H | I | J | K | L |

| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
|-------|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|-----|
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | O | N | D |

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|-----------------------------------|--------------|------------------------|------------------|-------|------|
| Drain-Source Voltage | | | V _{DSS} | -20 | V |
| Gate-Source Voltage | | | V _{GSS} | ±6 | V |
| Continuous Drain Current (Note 6) | Steady State | T _A = +25°C | I _D | -0.82 | A |
| | | T _A = +85°C | | -0.54 | |
| Pulsed Drain Current (Note 7) | | | I _{DM} | -3 | A |

Thermal Characteristics

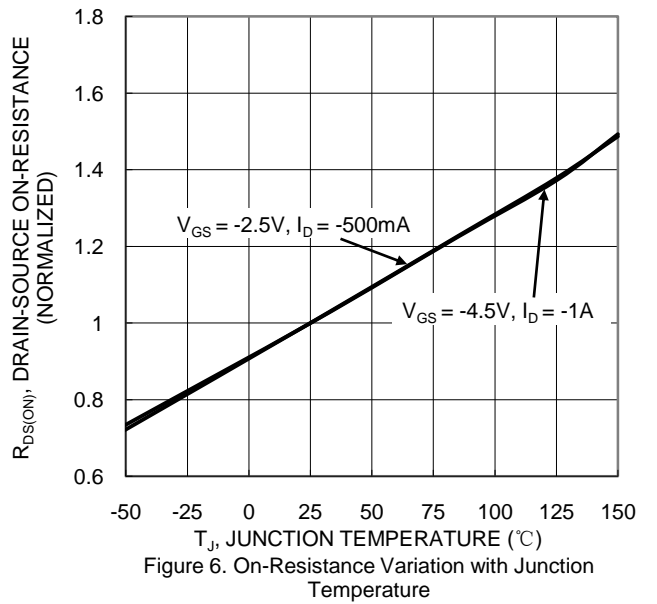
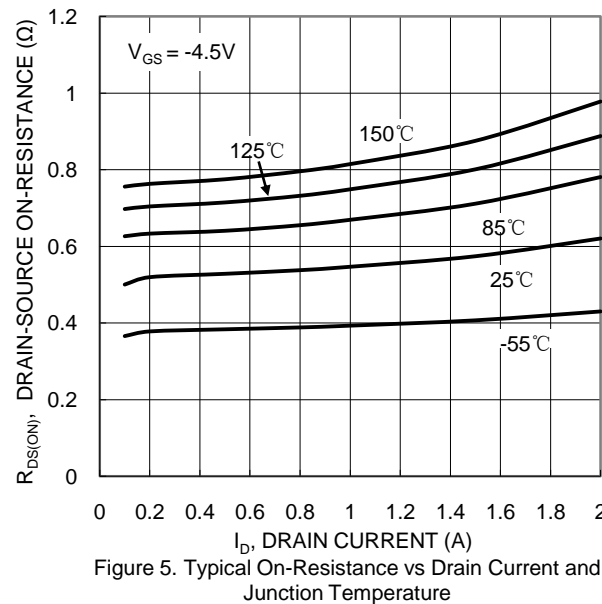
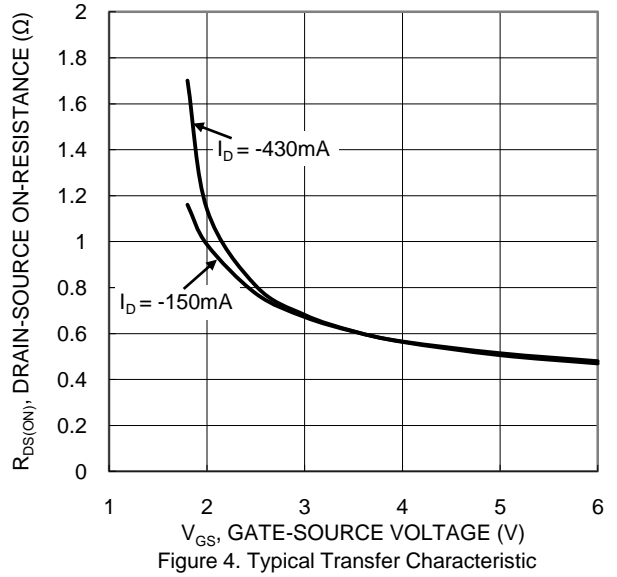
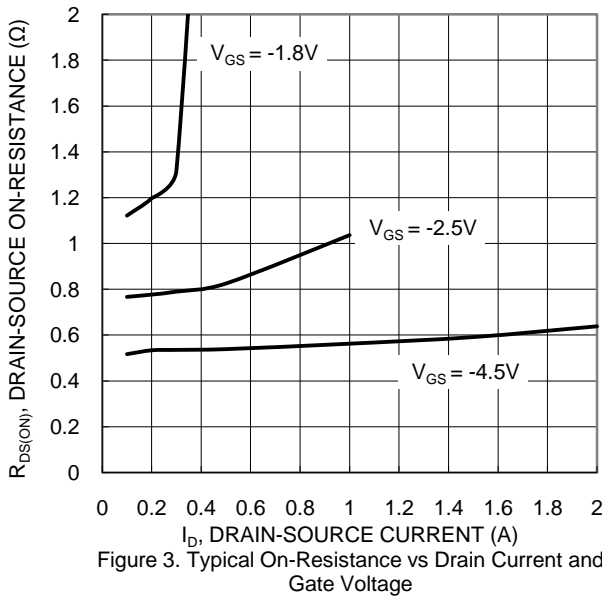
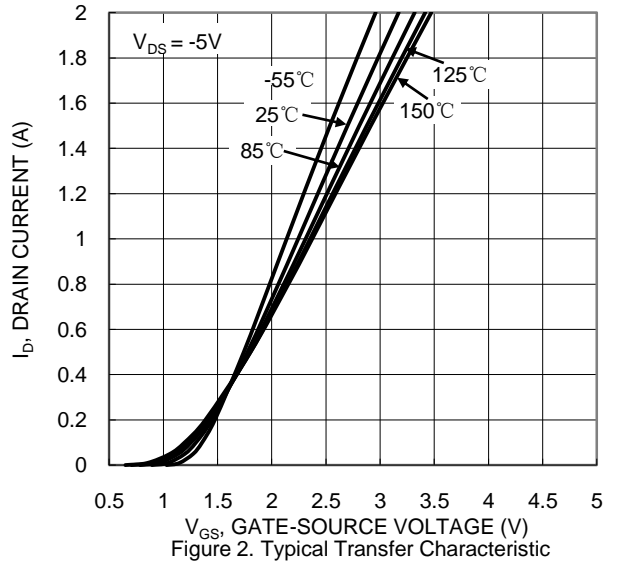
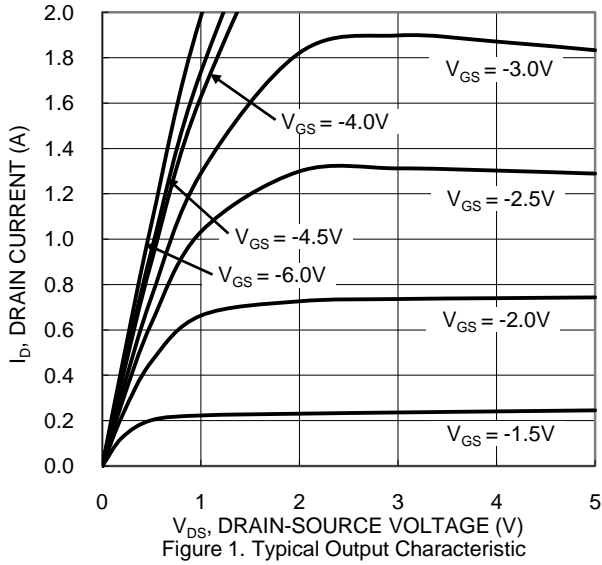
| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 6) | P _D | 0.31 | W |
| Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 6) | R _{θJA} | 398 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

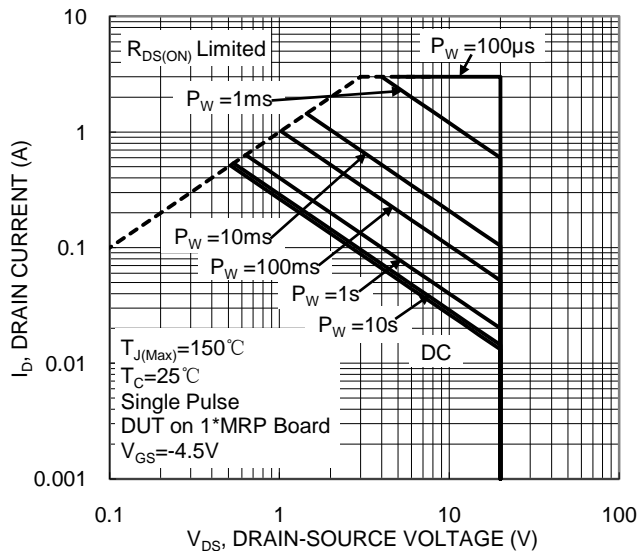
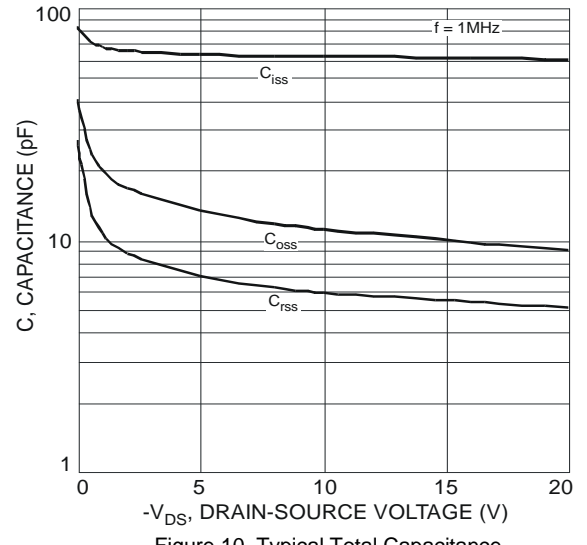
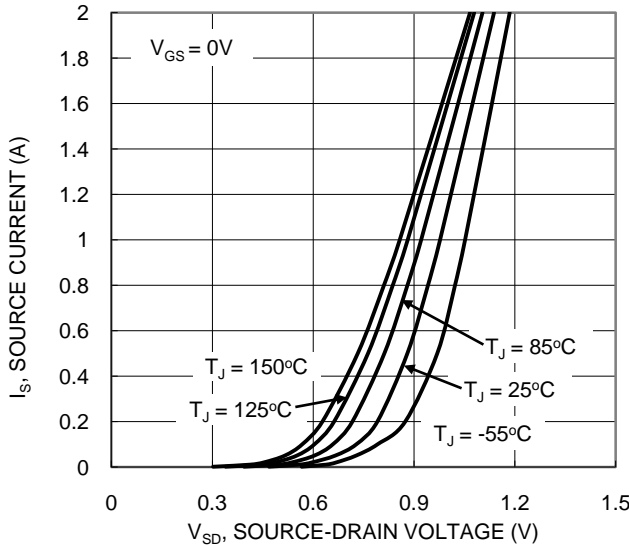
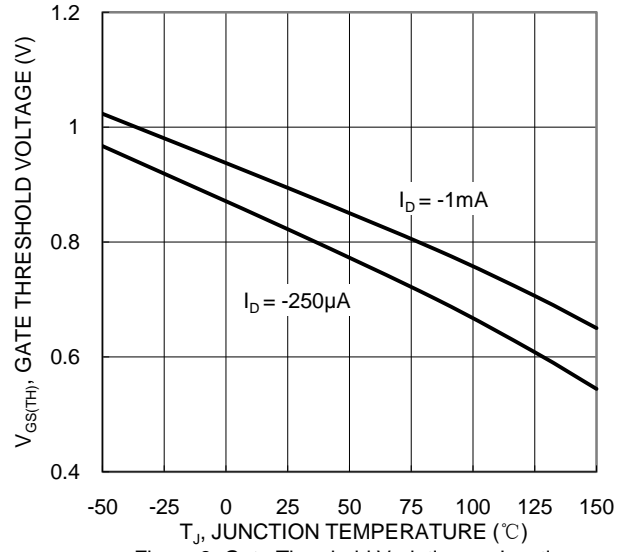
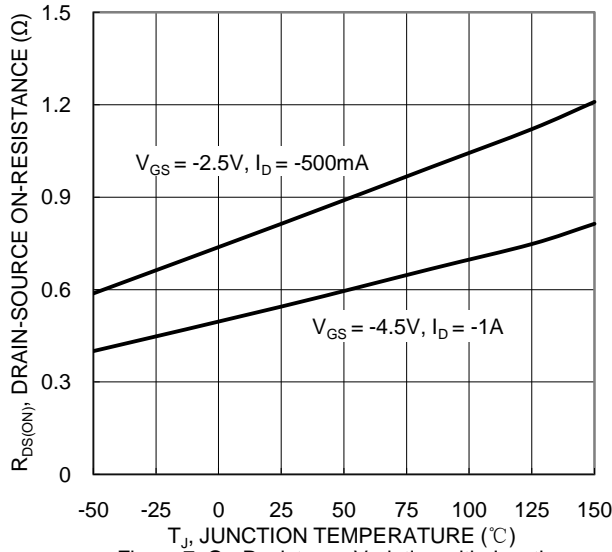
Notes: 6. Device mounted on FR-4 PCB, with minimum recommended pad layout.
7. Repetitive rating, pulse width limited by junction temperature.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|---------------------|------|-------|------|------|--|
| OFF CHARACTERISTICS (Note 8) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | -20 | - | - | V | V _{GS} = 0V, I _D = -250μA |
| Zero Gate Voltage Drain Current T _J = +25°C | I _{DSS} | - | - | -100 | nA | V _{DS} = -20V, V _{GS} = 0V |
| Gate-Source Leakage | I _{GSS} | - | - | ±2.0 | μA | V _{GS} = ±4.5V, V _{DS} = 0V |
| ON CHARACTERISTICS (Note 8) | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | -0.5 | - | -1.0 | V | V _{DS} = V _{GS} , I _D = -250μA |
| Static Drain-Source On-Resistance | R _{DS(ON)} | - | 0.5 | 0.75 | Ω | V _{GS} = -4.5V, I _D = -430mA |
| | | | 0.7 | 1.05 | | V _{GS} = -2.5V, I _D = -300mA |
| | | | 1.0 | 1.5 | | V _{GS} = -1.8V, I _D = -150mA |
| Forward Transfer Admittance | Y _{fs} | - | 0.9 | - | S | V _{DS} = -10V, I _D = -250mA |
| Diode Forward Voltage | V _{SD} | - | -0.8 | -1.2 | V | V _{GS} = 0V, I _S = -150mA |
| DYNAMIC CHARACTERISTICS (Note 9) | | | | | | |
| Input Capacitance | C _{iss} | - | 59.76 | - | pF | V _{DS} = -16V, V _{GS} = 0V, f = 1.0MHz |
| Output Capacitance | C _{oss} | - | 12.07 | - | pF | |
| Reverse Transfer Capacitance | C _{riss} | - | 6.36 | - | pF | |
| Total Gate Charge | Q _g | - | 622.4 | - | pC | V _{GS} = -4.5V, V _{DS} = -10V, I _D = -250mA |
| Gate-Source Charge | Q _{gs} | - | 100.3 | - | pC | |
| Gate-Drain Charge | Q _{gd} | - | 132.2 | - | pC | |
| Turn-On Delay Time | t _{D(ON)} | - | 5.1 | - | ns | V _{DD} = -10V, V _{GS} = -4.5V, R _L = 47Ω, R _G = 10Ω, I _D = -200mA |
| Turn-On Rise Time | t _R | - | 8.1 | - | ns | |
| Turn-Off Delay Time | t _{D(OFF)} | - | 28.4 | - | ns | |
| Turn-Off Fall Time | t _F | - | 20.7 | - | ns | |

Notes: 8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to production testing.





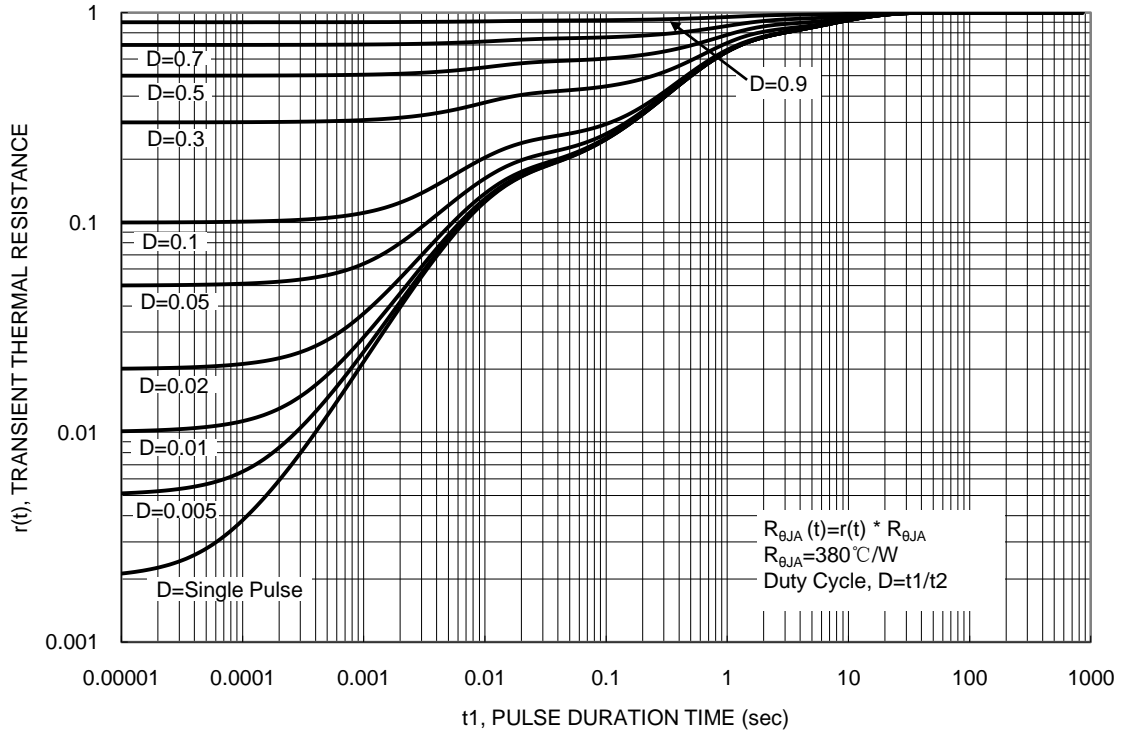
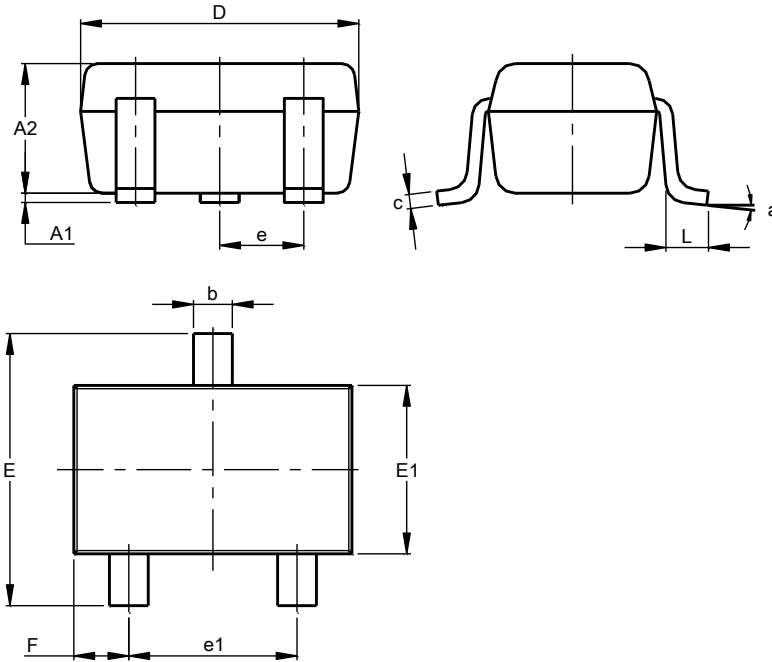


Figure 12. Transient Thermal Resistance

Package Outline Dimensions

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.

SOT323

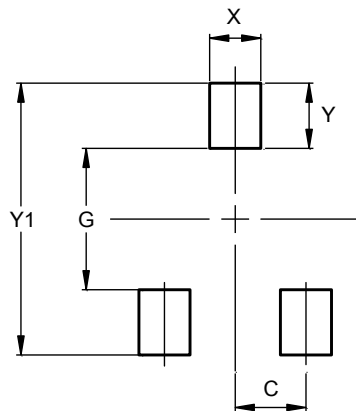


| SOT323 | | | |
|----------------------|-----------|-------|-------|
| Dim | Min | Max | Typ |
| A1 | 0.00 | 0.10 | 0.05 |
| A2 | 0.90 | 1.00 | 0.95 |
| b | 0.25 | 0.40 | 0.30 |
| c | 0.10 | 0.18 | 0.11 |
| D | 1.80 | 2.20 | 2.15 |
| E | 2.00 | 2.20 | 2.10 |
| E1 | 1.15 | 1.35 | 1.30 |
| e | 0.650 BSC | | |
| e1 | 1.20 | 1.40 | 1.30 |
| F | 0.375 | 0.475 | 0.425 |
| L | 0.25 | 0.40 | 0.30 |
| a | 8° | | |
| All Dimensions in mm | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.

SOT323



| Dimensions | Value (in mm) |
|------------|---------------|
| C | 0.650 |
| G | 1.300 |
| X | 0.470 |
| Y | 0.600 |
| Y1 | 2.500 |

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Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.